

STD60NF3LL

General features

Туре	V _{DSS}	R _{DS(on)}	I _D
STD60NF3LL	60V	<0.0095Ω	60A

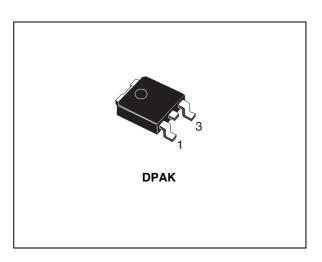
- Optimal R_{DS(ON)} x Q_g trade-off @ 4.5V
- Conduction losses reduced
- Switching losses reduced

Description

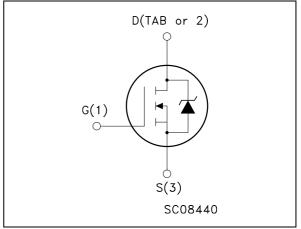
This application specific Power MOSFET is the third genaration of STMicroelectronics unique "Single Feature Size™" strip-based process. The resulting transistor shows the best trade-off between on-resistance ang gate charge. When used as high and low side in buck regulators, it gives the best performance in terms of both conduction and switching losses. This is extremely important for motherboards where fast switching and high efficiency are of paramount importance.

Applications

Switching application



Internal schematic diagram



Order codes

Part number	Marking	Package	Packaging
STD60NF3LLT4	D60NF3LL	DPAK	Tape & reel

Contents

1	Electrical ratings	3
2	Electrical characteristics	4
	2.1 Electrical characteristics (curves)	6
3	Test circuit	8
4	Package mechanical data	9
5	Packing mechanical data1	1
6	Revision history1	2



1 Electrical ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage ($V_{GS} = 0$)	30	V
V _{DGR}	Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) 30		V
V _{GS}	Gate- source voltage	± 16	V
I _D	Drain current (continuous) at $T_C = 25^{\circ}C$	60	A
۱ _D	Drain current (continuous) at $T_C = 100^{\circ}C$	43	A
I _{DM} ⁽¹⁾	Drain current (pulsed)	240	A
P _{tot}	Total dissipation at $T_C = 25^{\circ}C$	100	W
	Derating Factor	0.67	W/°C
$E_{AS}^{(2)}$	Single pulse avalanche energy	700	mJ
T _{stg}	Storage temperature		°C
Тj	Max. operating junction temperature	55 to 175	C

1. Pulse width limited by safe operating area.

2. Starting Tj=25°C, I_D =30A, V_{DD} =27.5V

Table 2. Thermal data

Rthj-case	Thermal resistance junction-case max	1.5	°C/W
Rthj-amb	Thermal resistance junction-to ambient max	100	°C/W
TJ	Maximum lead temperature for soldering purpose	300	°C

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	I _D = 250μΑ, V _{GS} =0	30			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = Max rating V_{DS} = Max rating, T_{C} = 125°C			1 10	μΑ μΑ
I _{GSS}	Gate-body leakage current (V _{DS} = 0)	$V_{GS} = \pm 16V$			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1			V
R _{DS(on)}	Static drain-source on resistance	$V_{GS} = 10V, I_D = 30A$ $V_{GS} = 4.5V, I_D = 30A$		0.0075 0.0085	0.0095 0.0105	Ω Ω

Table 3. On/off states

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
9 _{fs} ⁽¹⁾	Forward transconductance	V _{DS} = 15V, I _D = 30A		30		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V _{DS} = 25V, f = 1MHz, V _{GS} = 0		2210 635 138		pF pF pF
t _{d(on)} t _r t _{d(off)} t _f	Turn-on delay time Rise time Turn-off delay time Fall time	$V_{DD} = 15V, I_D = 30A$ $R_G = 4.7\Omega V_{GS} = 4.5V$ (see <i>Figure 12</i>)		22 130 36.5 36.5		ns ns ns ns
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 24V, I_D = 60A,$ $V_{GS} = 4.5V, R_G = 4.7\Omega$ (see <i>Figure 13</i>)		30 9 12.5	40	nC nC nC

1. Pulsed: Pulse duration = $300 \ \mu$ s, duty cycle 1.5 %.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{SD} I _{SDM} ⁽¹⁾	Source-drain current Source-drain current (pulsed)				60 240	A A
V _{SD} ⁽²⁾	Forward on voltage	$I_{SD} = 60A, V_{GS} = 0$			1.2	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 60A, di/dt = 100A/\mu s,$ $V_{DD} = 15V, T_j = 150^{\circ}C$ (see <i>Figure 14</i>)		65 105 3.4		ns nC A

Table 5.Source drain diode

1. Pulse width limited by safe operating area.

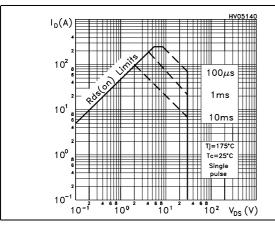
2. Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %



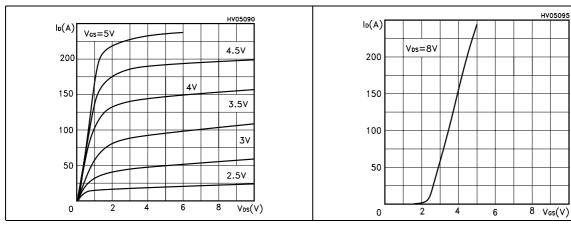
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Electrical characteristics (curves) 2.1

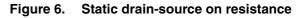
Figure 1. Safe operating area

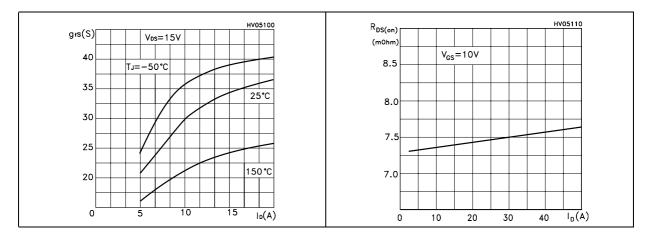


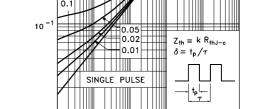










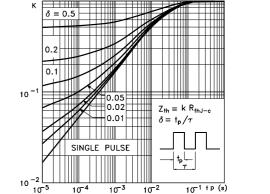


Transfer characteristics

Thermal impedance

Figure 2.

Figure 4.



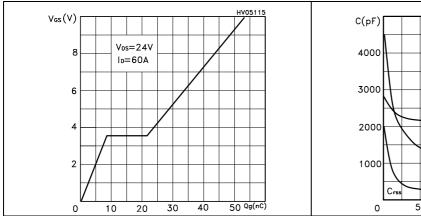


Figure 7. Gate charge vs gate-source voltage Figure 8. Capacitance variations

Figure 9. Normalized gate threshold voltage vs temperature

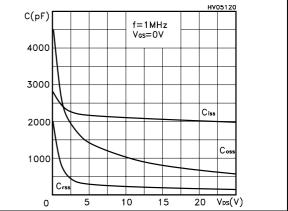


Figure 10. Normalized on resistance vs temperature

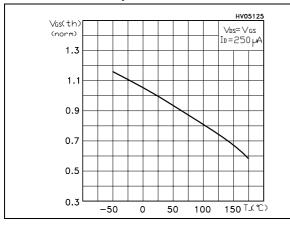
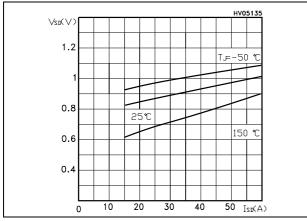
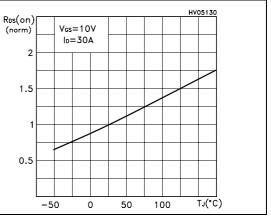


Figure 11. Source-drain diode forward characteristics







3 **Test circuit**

Figure 12. Switching times test circuit for resistive load

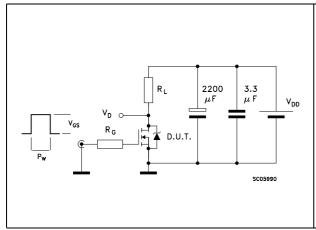
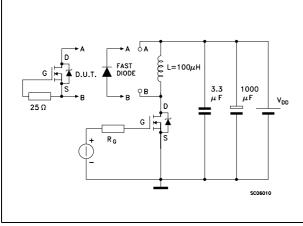


Figure 14. Test circuit for inductive load switching and diode recovery times





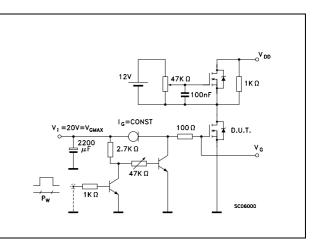


Figure 15. Unclamped Inductive load test circuit

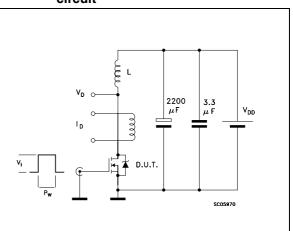


Figure 17. Switching time waveform

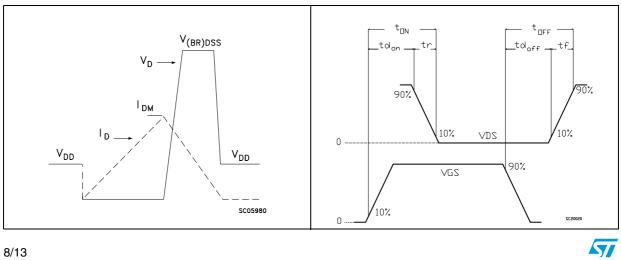


Figure 13. Gate charge test circuit

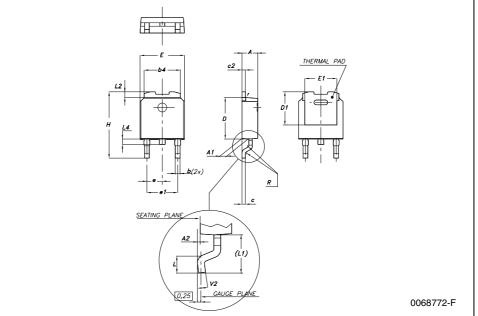
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



MIN. TYP MAX. MIN. TYP. MAX. A 2.2 2.4 0.086 0.05 A1 0.9 1.1 0.035 0.04 A2 0.03 0.23 0.001 0.00 B 0.64 0.9 0.025 0.03 b4 5.2 5.4 0.204 0.21 C 0.45 0.6 0.017 0.02 C 0.45 0.6 0.019 0.02 C 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.24 D1 5.1 0.204 0.200 0.24 D1 5.1 0.200 0.26 0.24 D1 5.1 0.200 0.26 0.24 E1 4.7 0.200 0.26 0.26 E1 4.7 0.185 0.38 0.38 H 9.35 10.1 0.368 0.38	DIM.		mm.			inch	
A1 0.9 1.1 0.035 0.04 A2 0.03 0.23 0.001 0.00 B 0.64 0.9 0.025 0.03 b4 5.2 5.4 0.204 0.21 C 0.45 0.6 0.017 0.02 C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.20 D 6 6.2 0.236 0.24 D1 5.1 0.200 0.24 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.000 0.026 E1 4.7 0.185 0.16 0.185 e 2.28 0.039 0.16 0.36 L 1 0.368 0.339 0.16 L1 2.8 0.039 0.110 1.02 L2 0.6 1 0.023 0.035	DIN.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
A2 0.03 0.23 0.001 0.00 B 0.64 0.9 0.025 0.03 b4 5.2 5.4 0.204 0.21 C 0.45 0.6 0.017 0.02 C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.20 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.6 0.173 e 2.28 0.090 0.185 0.185 L 1 0.368 0.39 0.39 L 1 0.039 0.110 0.185 L 1 0.039 0.110 0.185 L2 0.8 0.031 0.031 0.031	А	2.2		2.4	0.086		0.094
B 0.64 0.9 0.025 0.03 b4 5.2 5.4 0.204 0.21 C 0.45 0.6 0.017 0.02 C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.24 D1 5.1 0.200 0.26 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.000 0.026 E1 4.7 0.185 0.000 0.026 E1 4.7 0.185 0.090 0.090 e1 4.4 4.6 0.173 0.185 H 9.35 10.1 0.368 0.339 L 1 0.039 0.110 0.031 L2 0.8 1 0.023 0.035	A1	0.9		1.1	0.035		0.043
b4 5.2 5.4 0.204 0.21 C 0.45 0.6 0.017 0.02 C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.24 D1 5.1 0.200 0.26 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.26 e 2.28 0.090 0.185 H 9.35 10.1 0.368 0.33 L 1 0.039 0.110 0.18 L2 0.8 0.023 0.031 0.031	A2	0.03		0.23	0.001		0.009
C 0.45 0.6 0.017 0.02 C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.24 D1 5.1 0.20 0.24 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.090 0.185 e 2.28 0.036 0.390 0.185 H 9.35 10.1 0.368 0.338 L 1 0.039 0.110 0.185 L2 0.8 0.031 0.031 0.031	В	0.64		0.9	0.025		0.035
C2 0.48 0.6 0.019 0.02 D 6 6.2 0.236 0.24 D1 5.1 0.200 0.26 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.26 e 2.28 0.090 0.185 H 9.35 10.1 0.368 0.33 L 1 0.039 0.110 0.125 L2 0.8 0.031 0.031 0.031	b4	5.2		5.4	0.204		0.212
D 6 6.2 0.236 0.24 D1 5.1 0.200 0.26 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.26 e 2.28 0.090 0.185 e1 4.4 4.6 0.173 0.18 H 9.35 10.1 0.368 0.38 L 1 0.039 0.110 0.124 L2 0.8 0.8 0.031 0.031 L4 0.6 1 0.023 0.035	С	0.45		0.6	0.017		0.023
D1 5.1 0.200 E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.900 e 2.28 0.090 0.185 e1 4.4 4.6 0.173 0.18 H 9.35 10.1 0.368 0.38 L 1 0.039 0.110 0.110 L2 0.8 1 0.023 0.031	C2	0.48		0.6	0.019		0.023
E 6.4 6.6 0.252 0.26 E1 4.7 0.185 0.900 e 2.28 0.090 0.185 e1 4.4 4.6 0.173 0.185 H 9.35 10.1 0.368 0.39 L 1 0.039 0.110 0.110 L2 0.8 0.023 0.031 0.031 L4 0.6 1 0.023 0.035	D	6		6.2	0.236		0.244
E1 4.7 0.185 e 2.28 0.090 e1 4.4 4.6 0.173 0.18 H 9.35 10.1 0.368 0.39 L 1 0.039 0.110 0.110 L2 0.8 0.031 0.031 L4 0.6 1 0.023 0.035	D1		5.1			0.200	
e 2.28 0.090 e1 4.4 4.6 0.173 0.18 H 9.35 10.1 0.368 0.39 L 1 0.039 0.110 (L1) 2.8 0.110 0.031 L2 0.8 0.023 0.031	E	6.4		6.6	0.252		0.260
e1 4.4 4.6 0.173 0.18 H 9.35 10.1 0.368 0.39 L 1 0.039 0.110 0.12 (L1) 2.8 0.110 0.031 0.031 L2 0.8 0.023 0.031 0.031	E1		4.7			0.185	
H 9.35 10.1 0.368 0.368 L 1 0.039 0.110 0.110 (L1) 2.8 0.110 0.031 0.031 L2 0.8 0.023 0.031 L4 0.6 1 0.023 0.035	е		2.28			0.090	
L 1 0.039 0.110 (L1) 2.8 0.110 0.110 L2 0.8 0.031 0.031 L4 0.6 1 0.023 0.035	e1	4.4		4.6	0.173		0.181
(L1) 2.8 0.110 L2 0.8 0.031 L4 0.6 1 0.023 0.03	Н	9.35		10.1	0.368		0.397
L2 0.8 0.031 L4 0.6 1 0.023 0.03	L	1			0.039		
L4 0.6 1 0.023 0.03	(L1)		2.8			0.110	
	L2		0.8			0.031	
R 0.2 0.008	L4	0.6		1	0.023		0.039
	R		0.2			0.008	
V2 0° 8° 0° 8°	V2	0°		8°	0°		8°

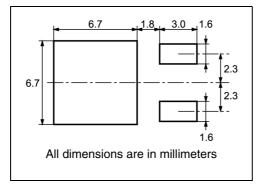
DPAK MECHANICAL DATA

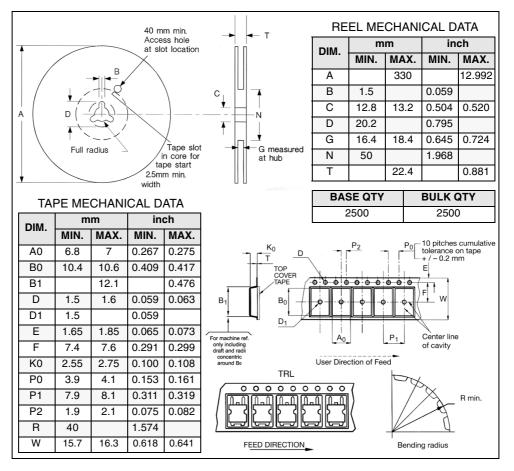




5 Packing mechanical data

DPAK FOOTPRINT





TAPE AND REEL SHIPMENT

57

6 Revision history

Date	Revision	Changes
09-Sep-2004	4	Preliminary version
19-Jul-2006	5	New template, no content change



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